# PerET

### 80V & 100V POWER MOSFET

Taiwan Semiconductor introduces PerFET™ 80V and 100V technology in the PDFN56U (5mm x 6mm) single and dual packages for high power, high switching frequency and high-performance requirement automotive applications. A portfolio of 18 items, including both normal-level (10V) and logic-level (5V) gate drive types, enables customers to select the best-fit product for their design. All of this enables the Best-in-class FOM (R<sub>DS(on)</sub> \* Q<sub>g</sub>) and Performance in the market.

The PDFN56U wettable flank package offers improved solder joint quality and enhanced AOI accuracy. Additionally, it is highly footprint-compatible with the majority of 5mm × 6mm packages on the market.







Official Website

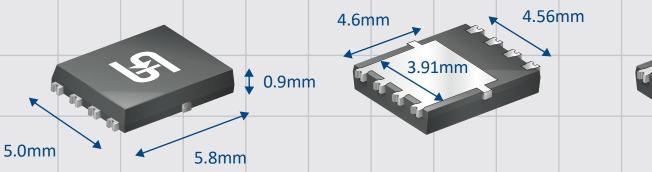
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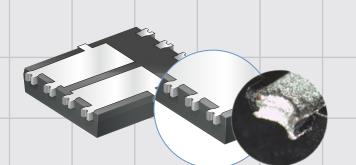
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For more questions: marketing@ts.com.tw

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## PACKAGE PDFN56U PDFN56DU





Wettable flank leads improve solder joint reliability and AOI's accuracy during PCB assembly process.

#### **SPECIFICATION**

	Part Number	<b>V</b> <sub>DS</sub> (V)	R <sub>DS(ON)</sub> max. 10V (mΩ)	R <sub>DS(ON)</sub> max. 4.5V (mΩ)	ID Tc=25°C (A)	V <sub>GSTH</sub> (V)	$Q_{G}^{typ}$ $V_{gs}^{= 10V}$ (nC)	Package	
	TQM048NH10LCR RLG	100	4.8	6.1	100	1.4~2.2	47	PDFN56U	
	TQM048NH10CR RLG		4.8	-	100	2.4~3.6	35		
	TQM075NH10LCR RLG		7.5	9.4	100	1.4~2.2	36		
	TQM075NH10CR RLG		7.5	-	100	2.4~3.6	22		
	TQM100NH10LCR RLG		10	12	81	1.4~2.2	25		
	TQM100NH10CR RLG		10	-	72	2.4~3.6	20		
	TQM170NH10LCR RLG		17	20	72	1.4~2.2	17		
	TQM170NH10CR RLG		17	-	50	2.4~3.6	11		
	TQM240NH10LCR RLG		24	29	50	1.4~2.2	9.3		
	TQM240NH10CR RLG		24	-	34	2.4~3.6	8.1		
	TQM250NH10LDCR RLG		25	30	34	1.4~2.2	10	PDFN56UD	
	TQM250NH10DCR RLG		25	-	31	2.4~3.6	8.4		
	TQM058NH08LCR RLG	80	5.8	8.1	100	1.4~2.2	35	PDFN56U	
	TQM063NH08CR RLG		6.3	-	100	2.4~3.6	27		
	TQM130NH08LCR RLG		13	18.2	54	1.4~2.2	17		
	TQM145NH08CR RLG		14.5	-	52	2.4~3.6	13		
	TQM210NH08LDCR RLG		21	29.4	33	1.4~2.2	11	PDFN56UD	
	TQM230NH08DCR RLG		23	-	31	2.4~3.6	9.1		

#### **FEATURES**



LOWER PARASITIC CAPACITANCE



LOWER TEMPERATURE COEFFICIENT

The R<sub>DS(ON)</sub> value at temperatures of

-55 °C ~ 175°C

presented less variation.



AUTOMOTIVE AEC-Q101
QUALIFIED



EXCELLENT FOM (Q<sub>g</sub> x R<sub>DS(ON)</sub>)

#### **APPLICATIONS**



**AUTOMOTIVE** 



MOTOR



**TELECOM** 



DC/DC CONVERTER



**MICROINVERTER** 



POWER SUPPLY



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